Vishay Semiconductors



FEATURES

- Ultrafast recovery time, reduced Q_{rr} and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM, snubber operation
- Low forward voltage drop
- Low leakage current
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, ultrafast recovery time, and fast recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Peak repetitive reverse voltage	V _{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	$T_{L} = 110 \ ^{\circ}C \ ^{(1)}$	3	٨				
Non-repetitive peak surge current per leg	I _{FSM}	$T_J = 25 \text{ °C}, 6 \text{ ms}$ square pulse	55	A				
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C				

Note

⁽¹⁾ Mounted on PCB with minimum pad size

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
	VF	I _F = 3 A	-	1.15	1.35	V	
Forward voltage V _F		I _F = 3 A, T _J = 150 °C	-	0.99	1.2		
		$V_{R} = V_{R}$ rated	-	-	3		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	100	μΑ	
Junction capacitance	CT	V _R = 600 V	-	3.9	-	pF	

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SMB (DO-214AA)

PRIMARY CHARACTERISTICS						
I _{F(AV)}	3 A					
V _R	600 V					
V _F at I _F	0.99 V					
t _{rr} typ.	41 ns					
T _J max.	175 °C					
Package	SMB (DO-214AA)					
Circuit configuration	Single					

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RoHS

COMPLIANT

HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \ dI_F/dt = 10$	I _F = 1.0 A, dI _F /dt = 100 A/μs, V _R = 30 V		41	-		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$	0 Α/μs, V _R = 30 V	-	52	-		
Reverse recovery time t _{rr}	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	65	ns	
		T _J = 25 °C		-	38	-		
		T _J = 125 °C		-	52	-		
Pools receivers ourrent		$T_J = 25 \text{ °C}$ $I_F = 3 \text{ A}$	-	5.6	-	А		
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 200 A/µs V _R = 390 V	-	7.3	-	~	
David and a state of the state	0	T _J = 25 °C		-	108	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	193	-		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to case	R _{thJC} ⁽¹⁾		-	-	18	°C/W
Thermal resistance, junction to ambient	R _{thJA} ⁽¹⁾		-	-	90	0/10
Annewimete Weight				0.1		g
Approximate Weight			0.003			oz.
Marking device		Case style SMB (DO-214AA)		31	J6	

Note

⁽¹⁾ Mounted on PCB with minimum pad size

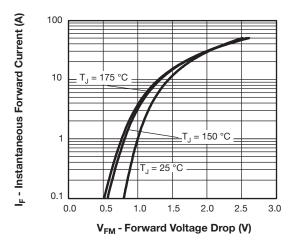


Fig. 1 - Typical Forward Voltage Drop Characteristics

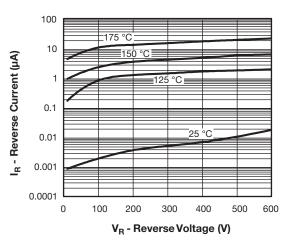


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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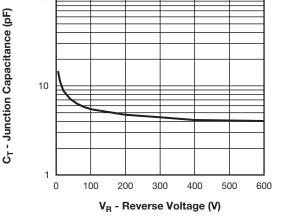
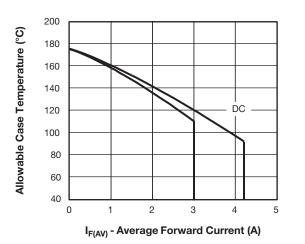
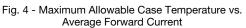


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





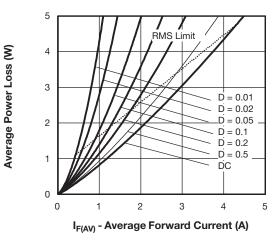


Fig. 5 - Forward Power Loss Characteristics

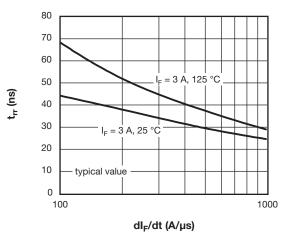
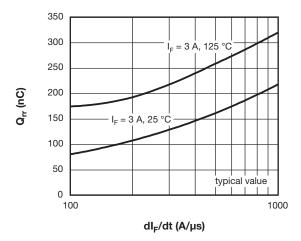
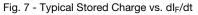


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt





VS-3EGU06-M3

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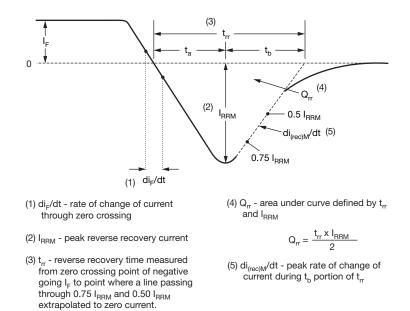


Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	′S-	3	Е	G	U	06	-M3
(-	1	2	3	4	5	6	7
1 2 3	-	Cur Circ	rent rati	niconduo ng (3 = 3 iguratior	3 A)	oduct	
4 5 6 7	- - -	G = Pro U = Volt	SMB pa cess typ ultrafas age coo	ackage	600 V)	complia	int, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-3EGU06-M3/5BT	5BT	3200	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95401				
Part marking information	www.vishay.com/doc?95472				
Packaging information	www.vishay.com/doc?95404				
SPICE model	www.vishay.com/doc?96667				
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